



## JR0805C 8A SCR

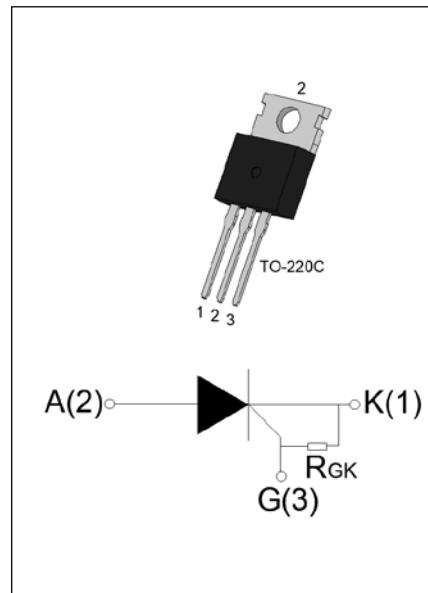
Rev.A.1.0

## DESCRIPTION:

The JR0805C SCR with the parallel resistor between Gate and Cathode,  $R_{GK}=10\sim80k\Omega$ , is especially recommended for use on straight hair, igniter, anion generator, etc. Package TO-220C is RoHS compliant.

## MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	8	A
$V_{DRM}/V_{RRM}$	600	V
$I_{GT}$	$\leq 200$	$\mu A$



## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	°C
Operating junction temperature range	$T_j$	-40-125 <sup>①</sup>	°C
Repetitive peak off-state voltage ( $T_j=25^\circ C$ )	$V_{DRM}$	600	V
Repetitive peak reverse voltage ( $T_j=25^\circ C$ )	$V_{RRM}$	600	V
Average on-state current ( $T_c \leq 109^\circ C$ )	$I_{T(AV)}$	5	A
RMS on-state current ( $T_c \leq 109^\circ C$ )	$I_{T(RMS)}$	8	A
Non repetitive surge peak on-state current ( $t_p=10ms, T_j=25^\circ C$ )	$I_{TSM}$	80	A
Non repetitive surge peak on-state current ( $t_p=8.3ms, T_j=25^\circ C$ )		88	
$I^2t$ value for fusing ( $t_p=10ms, T_j=25^\circ C$ )	$I^2t$	32	$A^2s$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}, f=100Hz, T_j=125^\circ C$ )	$di/dt$	50	$A/\mu s$
Peak gate current ( $t_p=20\mu s, T_j=125^\circ C$ )	$I_{GM}$	4	A
Average gate power dissipation ( $T_j=125^\circ C$ )	$P_{G(AV)}$	1	W

Peak gate power	$P_{GM}$	5	W
Peak pulse voltage ( $T_j=25^\circ\text{C}$ ; non-repetitive, off-state; FIG.7)	$V_{pp}$	0.5	kV

**NOTE 1:** When we parallel connect a  $\leq 1\text{K}\Omega$  resistor between Gate and Cathode, the  $T_j$  can reach  $125^\circ\text{C}$ ; if without this resistor, the  $T_j$  only can reach  $110^\circ\text{C}$ .

### ELECTRICAL CHARACTERISTICS ( $T_j=25^\circ\text{C}$ unless otherwise specified)

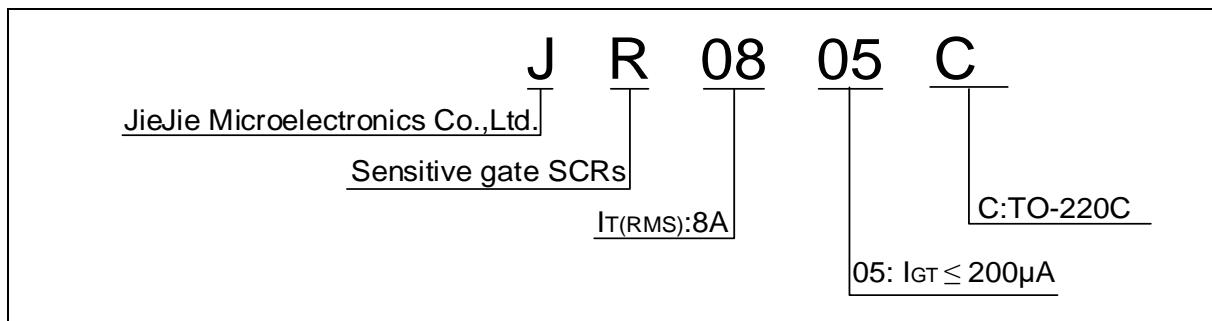
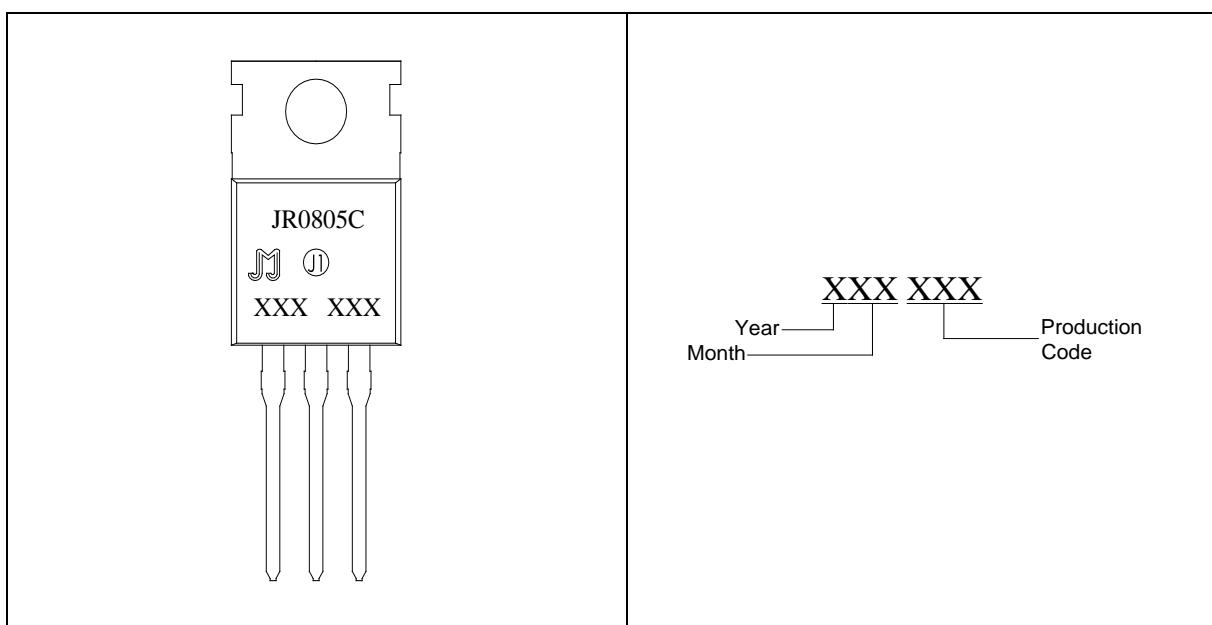
Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
$I_{GT}$	$V_D=12\text{V}$ $R_L=33\Omega$	-	-	200	$\mu\text{A}$
$V_{GT}$		-	-	0.8	V
$V_{GD}$	$V_D=V_{DRM}$ $T_j=125^\circ\text{C}$	0.2	-	-	V
$I_L$	$I_G=1.2 I_{GT}$	-	-	6	mA
$I_H$	$I_T=0.1\text{A}$	-	-	5	mA
$dV/dt$	$V_D=400\text{V}$ $T_j=125^\circ\text{C}$ $R_{GK}=1\text{K}\Omega$	50	-	-	V/ $\mu\text{s}$
	$V_D=400\text{V}$ $T_j=125^\circ\text{C}$ $R_{GK}=220\Omega$	250	-	-	
$t_{on}$	$I_G=10\text{mA}$ $I_A=20\text{mA}$ $I_R=2\text{mA}$ $T_j=25^\circ\text{C}$	-	2	-	$\mu\text{s}$
$t_{off}$		-	50	-	

### STATIC CHARACTERISTICS

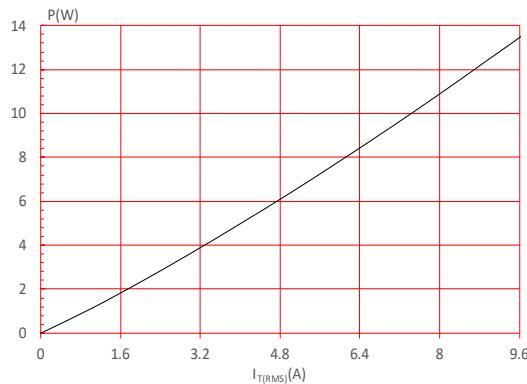
Symbol	Parameter	Value(MAX.)	Unit	
$V_{TM}$	$I_{TM}=16\text{A}$ $t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	1.55	V
$V_{TO}$	Threshold voltage	$T_j=125^\circ\text{C}$	0.79	V
$R_D$	Dynamic resistance	$T_j=125^\circ\text{C}$	0.02	$\Omega$
$I_{DRM}$	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25^\circ\text{C}$	5	$\mu\text{A}$
$I_{RRM}$		$T_j=125^\circ\text{C}$	0.5	mA

### THERMAL RESISTANCES

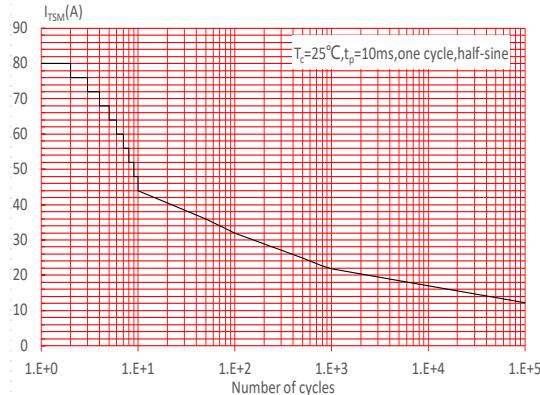
Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (DC)	1.5	$^\circ\text{C}/\text{W}$
$R_{th(j-a)}$	junction to ambient (DC)	40	$^\circ\text{C}/\text{W}$

**ORDERING INFORMATION****MARKING**

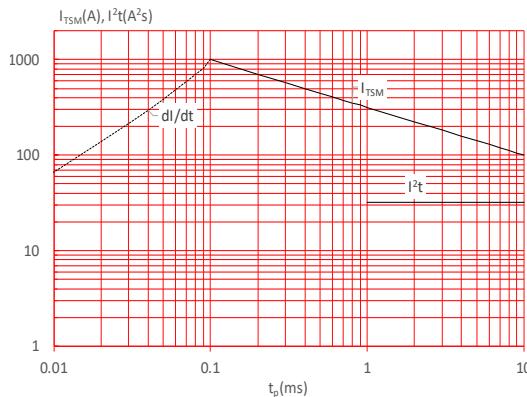
**FIG.1** Maximum power dissipation versus RMS on-state current



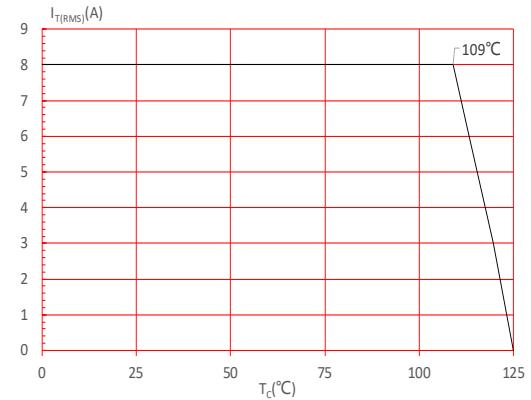
**FIG.3:** Surge peak on-state current versus number of cycles



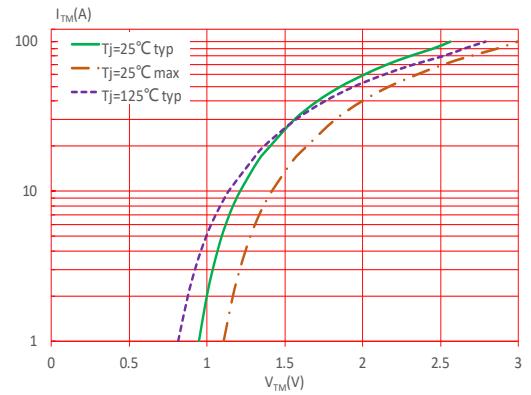
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$ , and corresponding value of  $I^2t$  ( $dl/dt < 50\text{A}/\mu\text{s}$ )



**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

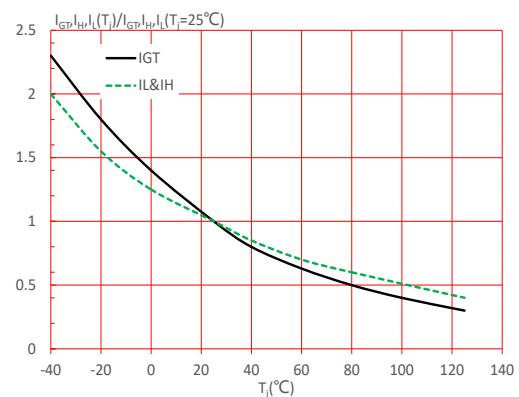
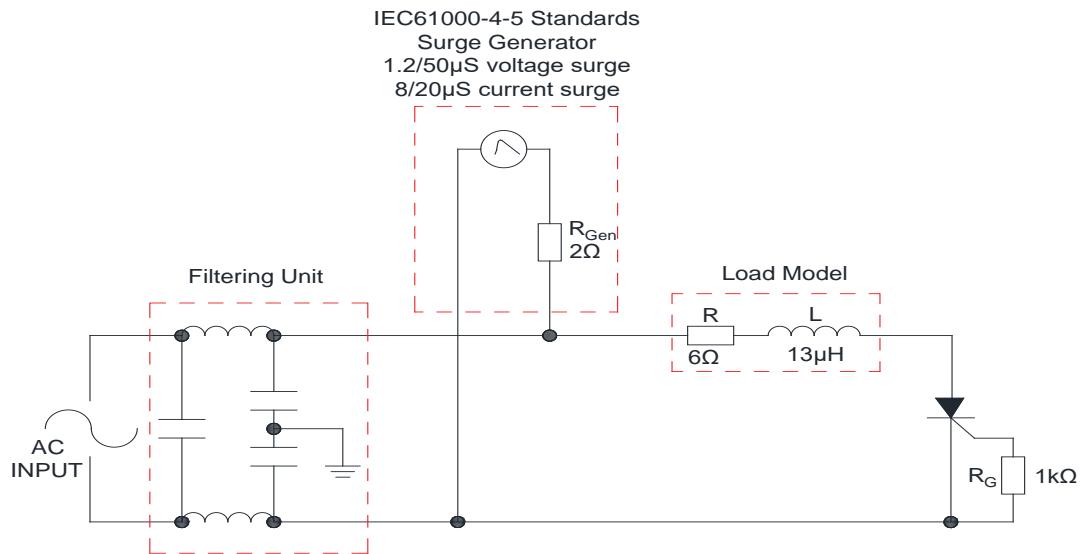


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



## SHAPING AND SOLDERING PARAMETERS

Refer to 《Instructions for installation of plastic-sealed in-line power devices》 released by JieJie

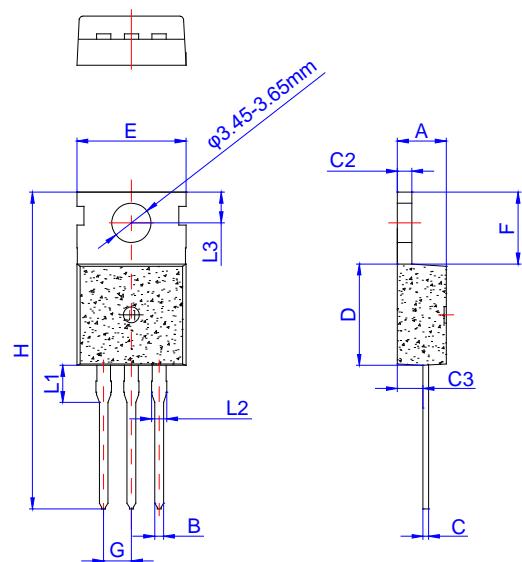
**ORDERING INFORMATION**

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(μA)	Package	Base qty. (pcs)	Delivery mode
JR0805C	600	≤200	TO-220C	50	Tube

**Document Revision History**

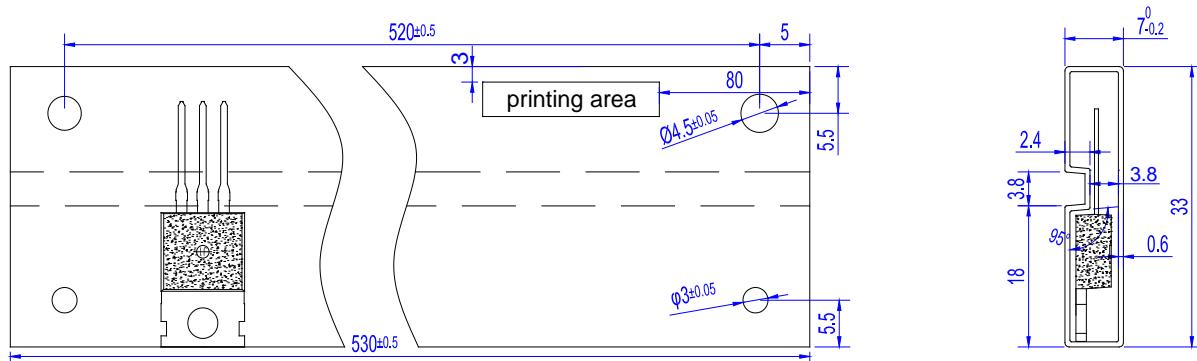
Date	Revision	Changes
Apr.10, 2023	A.1.0	Last update

## PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.70		0.90	0.028		0.035
C	0.45		0.60	0.018		0.024
C2	1.25		1.35	0.049		0.053
C3	2.20		2.60	0.087		0.102
D	8.90		9.90	0.350		0.390
E	9.90		10.3	0.390		0.406
F	6.30		6.90	0.248		0.272
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	2.70		3.30	0.106		0.130
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116

## DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220C	TUBE	50	1,000	5,000

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